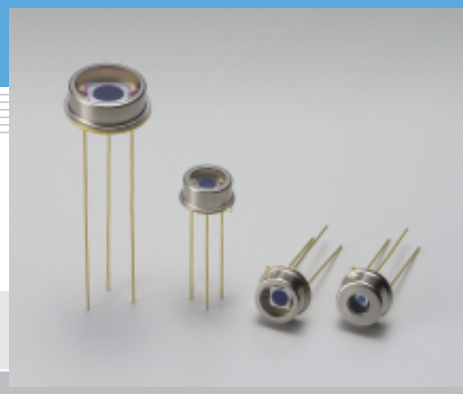


Si PIN photodiode S3071, S3072, S3399, S3883

Large area, high-speed Si PIN photodiodes



S3071, S3072, S3399 and S3883 are Si PIN photodiodes having a relatively large active area from $\phi 1.5$ to $\phi 5.0$ mm yet they offer excellent frequency response from 40 to 300 MHz. These photodiodes are suitable for spatial light transmission and high-speed pulsed light detection.

Features

- Active area size
S3071: $\phi 5.0$ mm
S3072: $\phi 3.0$ mm
S3399: $\phi 3.0$ mm
S3883: $\phi 1.5$ mm
- Cut-off frequency
S3071: 40 MHz ($V_R=24$ V)
S3072: 45 MHz ($V_R=24$ V)
S3399: 100 MHz ($V_R=10$ V)
S3883: 300 MHz ($V_R=20$ V)
- High reliability: TO-5/8 metal package

Applications

- Spatial light transmission
- High-speed pulsed light detection

General ratings / Absolute maximum ratings

Type No.	Dimensional outline/ Window material *1	Package (mm)	Active area size (mm)	Effective active area (mm ²)	Absolute maximum ratings			
					Reverse voltage V _R Max. (V)	Power dissipation P (mW)	Operating temperature T _{opr} (°C)	Storage temperature T _{stg} (°C)
S3071	①/K	TO-8	φ5.0	19.6	50	50	-40 to +100	-55 to +125
S3072	②/K	TO-5	φ3.0	7.0				
S3399	③/K		φ3.0	7.0				
S3883	④/K		φ1.5	1.7				

Electrical and optical characteristics (Typ. $T_a=25$ °C, unless otherwise noted)

Type No.	Spectral response range λ (nm)	Peak sensitivity wavelength λ_p (nm)	Photo sensitivity S (A/W)				Short circuit current I_{sc} 100 lx (μ A)	Dark current I_D (nA)		Temp. coefficient of I_D T_{CID} (times/°C)	Cut-off frequency f_c $R_L=50\ \Omega$ (MHz)	Terminal capacitance C_t $f=1\text{ MHz}$ (pF)	NEP $\lambda=\lambda_p$ (W/Hz ^{1/2})						
			λ_p	660 nm	780 nm	830 nm		Typ.	Max.										
S3071	320 to 1060	920	0.6	0.47	0.54	0.56	17	0.5 ^{*3}	10 ^{*3}	1.15	40 ^{*3}	18 ^{*3}	2.1 × 10 ⁻¹⁴ ^{*3}						
S3072							6.5	0.3 ^{*3}	10 ^{*3}		45 ^{*3}	7 ^{*3}	1.6 × 10 ⁻¹⁴ ^{*3}						
S3399							320 to 1000	840	0.6	0.45	0.58	0.6	5.6	0.1 ^{*4}	1.0 ^{*4}	1.12	100 ^{*4}	20 ^{*4}	9.4 × 10 ⁻¹⁵ ^{*4}
S3883													1.4	0.05 ^{*2}	1.0 ^{*2}		300 ^{*2}	6 ^{*2}	6.7 × 10 ⁻¹⁵ ^{*2}

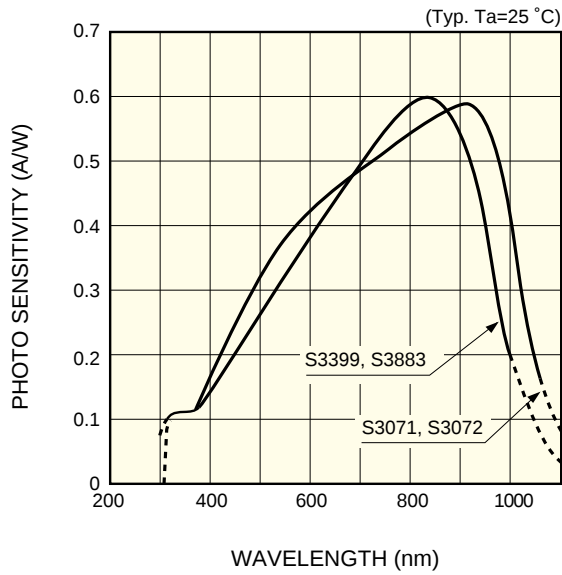
*1: Window material K: borosilicate glass

*2: $V_R=20$ V

*3: $V_R=24$ V

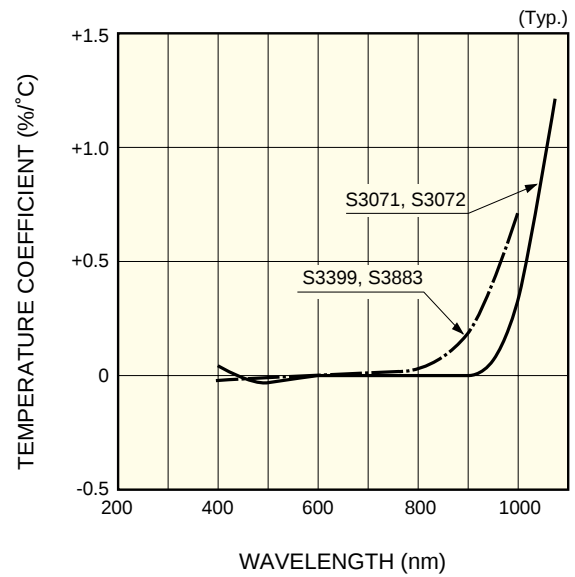
*4: $V_R=10$ V

■ Spectral response



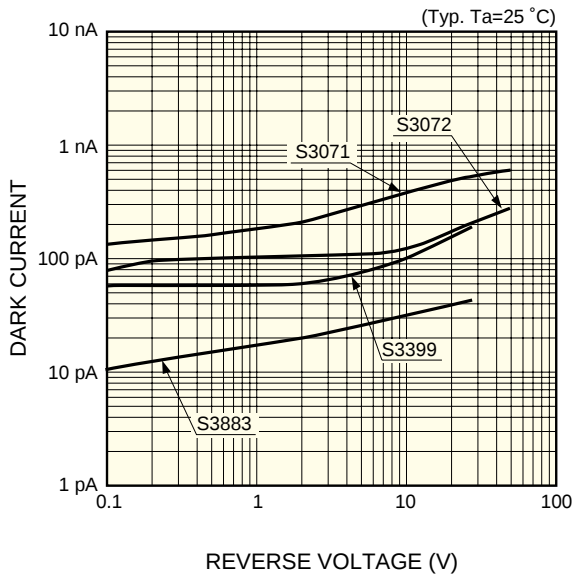
KPINB0147EA

■ Photo sensitivity temperature characteristics



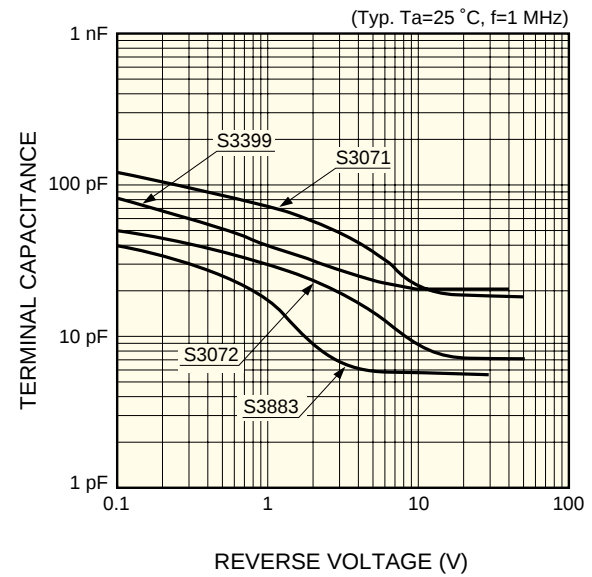
KPINB0148EA

■ Dark current vs. reverse voltage



KPINB0149EA

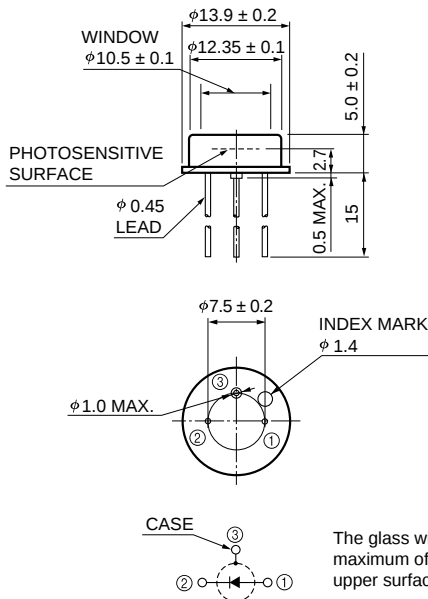
■ Terminal capacitance vs. reverse voltage



KPINB0150EA

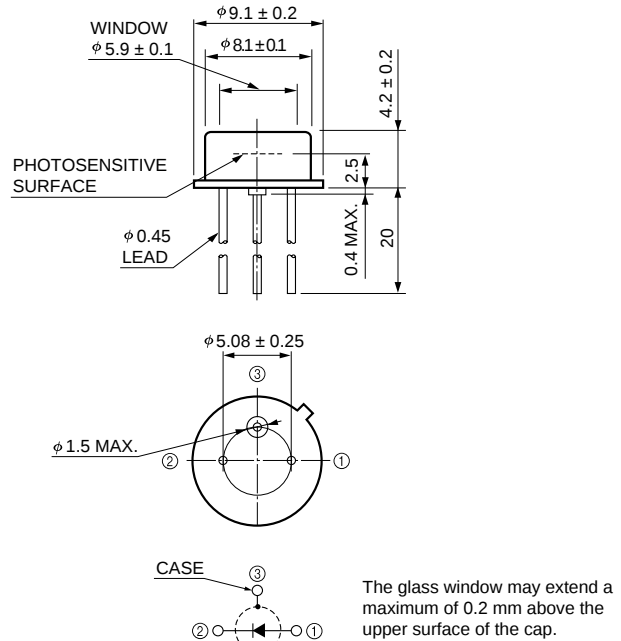
■ Dimensional outline (unit: mm)

① S3071



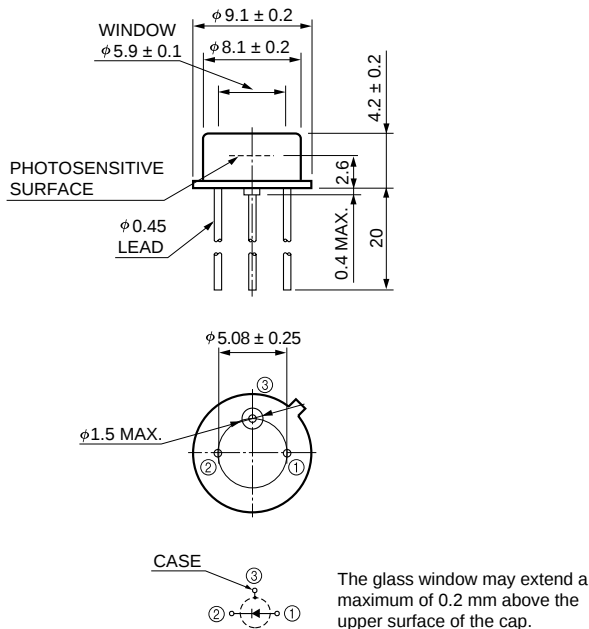
KPINA0027EC

② S3072



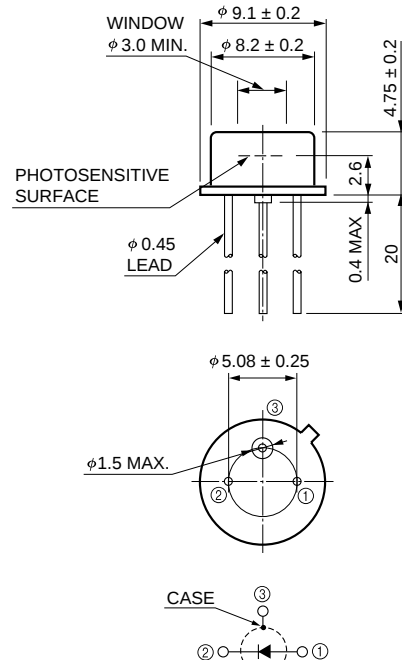
KPINA0024EB

③ S3399



KPINA0026EA

④ S3883



KPINA0025EB

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